IN THE CLAIMS

(Original) A method of forming a device including emitters comprising:
exposing a first face of a sheet of bundled fiber segments to a reactive liquid to
allow first ends of said fiber segments to react with said reactive liquid to remove
material therefrom;

depositing a coating material on said first face with said material removed; and exposing a second face of said sheet of bundled fiber segments to a reactive liquid to allow second ends of said fiber segments to react with said reactive liquid to remove material therefrom to expose said coating material.

- 2. (Original) The method of Claim 1, wherein said reactive liquid comprises a bath of HF acid.
- (Previously presented) The method of Claim 1, wherein said reactive liquid comprises a spray of HF acid.
- 4. (Currently amended) The method of Claim 1, wherein said coating material comprises a low electron affirnity material taken from the group consisting of α-C, PdO_x, Pd, Mo, Ni, Cr, Cu, Au, Pt, Ir, and diamond and the like.
- 5. (Original) The method of Claim 1, wherein said exposing said first face of said sheet of bundled fiber segments to a reactive liquid comprises removing material from said first ends to form modified ends and cells, wherein depositing said coating material on said

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- 6. (Original) The method of Claim 1, further comprising forming a dielectric layer on said coating material.
- 7. (Original) The method of Claim 6, further comprising mounting a substrate on said dielectric layer.
- 8. (Original) The method of Claim 1, wherein said exposed coating material forms an electron emitter.
 - 9. (Original) The method of Claim 1, further comprising: providing a transparent substrate having a transparent conductive material deposited thereon;

forming a dielectric spacer on said transparent substrate; patterning and etching selective areas of said dielectric spacer to form chambers for containing color phosphors; and

aligning said etched selective areas with said exposed coating material to form a field emitter device.

- (Original) The method of Claim 9, wherein a gate electrode is formed on said 10. dielectric spacer.
 - (Original) The method of Claim 9, further comprising:
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LANY OFFICES OF MacPherson Kwo Chen & Heid Llp 1762 Technology Drive Sultz 726 Sau Jew, CA 95110 (949) 752-7040 FAX (949) 752-7049 depositing a transparent conductive material on said transparent substrate, and patterning said transparent conductive material.

- 12. (Original) The method of Claim 9, further comprising: sealing said field emitter device after pumping said field emitter device into vacuum.
- 13. (Original) The method of Claim 1, wherein a gate electrode layer is deposited and patterned on the second face of said sheet of bundled fiber segments.

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